

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM6N03FE

High Speed Switching Applications

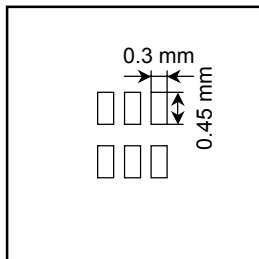
Analog Switch Applications

- Input impedance is high. Driving current is extremely low.
- Can be directly driven by a CMOS device even at low voltage due to low gate threshold voltage.
- High-speed switching.
- Housed in a ultra-small package which is suitable for high density mounting.

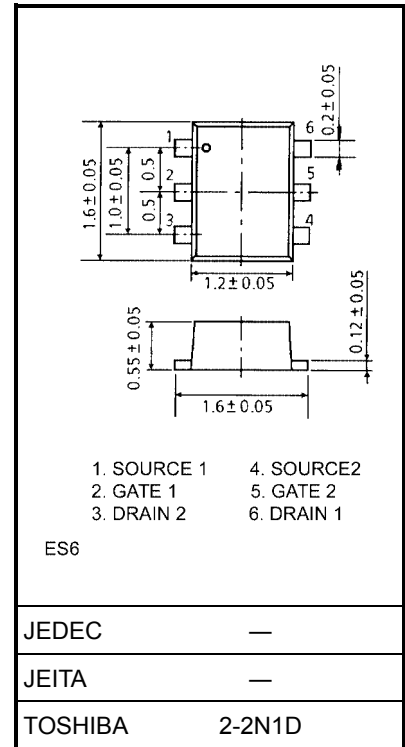
Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	20	V
Gate-source voltage	V _{GSS}	10	V
Drain current	I _D	100	mA
Drain power dissipation	P _D (Note 1)	150	mW
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55~150	°C

Note 1: Total rating, mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.135 mm² × 6)

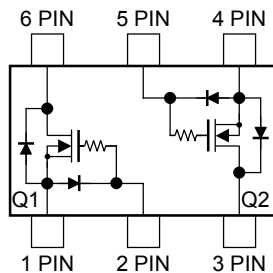


Unit: mm

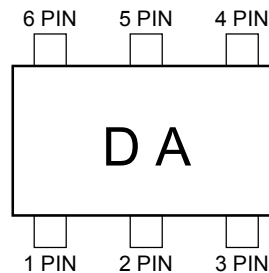


Weight: g (typ.)

Equivalent Circuit (top view)



Marking

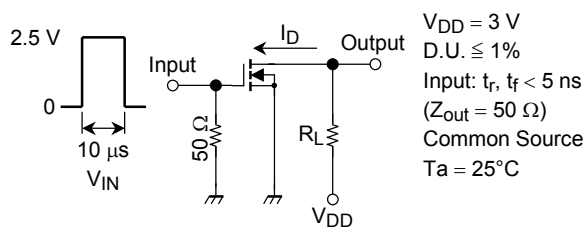


Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = 10\text{ V}, V_{DS} = 0\text{ V}$	—	—	1	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 100\ \mu\text{A}, V_{GS} = 0\text{ V}$	20	—	—	V
Drain cut-off current		I_{DSS}	$V_{DS} = 20\text{ V}, V_{GS} = 0\text{ V}$	—	—	1	μA
Gate threshold voltage		V_{th}	$V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$	0.7	—	1.3	V
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 10\text{ mA}$	25	50	—	mS
Drain-source ON resistance		$R_{DS(ON)}$	$I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$	—	4	12	Ω
Input capacitance		C_{iss}	$V_{DS} = 3\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	11.0	—	pF
Reverse transfer capacitance		C_{rSS}	$V_{DS} = 3\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	3.3	—	pF
Output capacitance		C_{oss}	$V_{DS} = 3\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	9.3	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0\sim 2.5\text{ V}$	—	0.16	—	μs
	Turn-off time	t_{off}	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0\sim 2.5\text{ V}$	—	0.19	—	

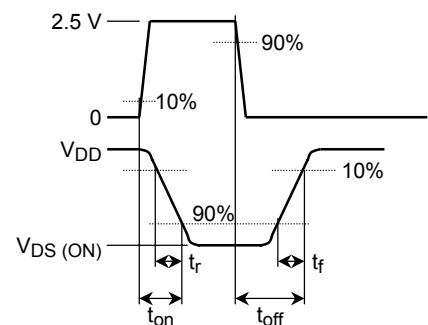
Switching Time Test Circuit

(a) Test circuit



(b) V_{IN}
 V_{GS}

(c) V_{OUT}
 V_{DS}

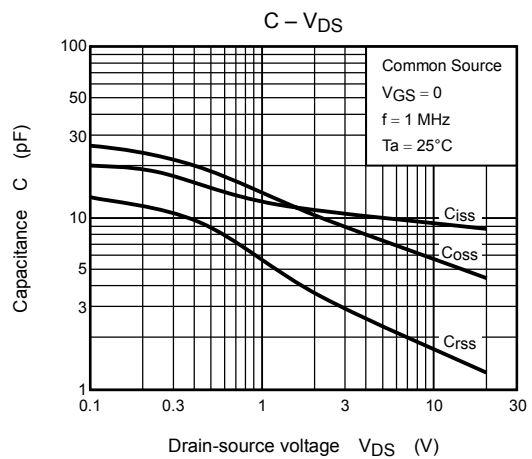
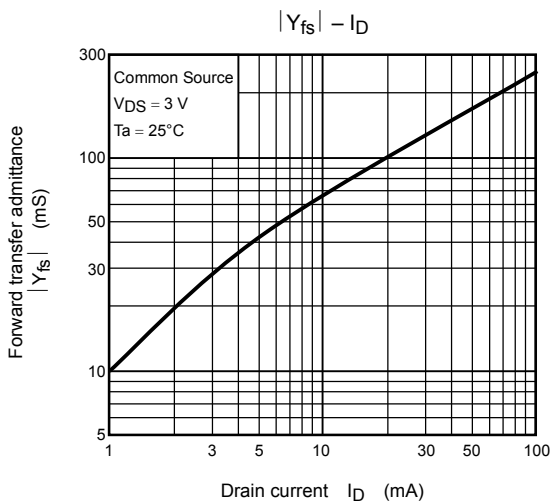
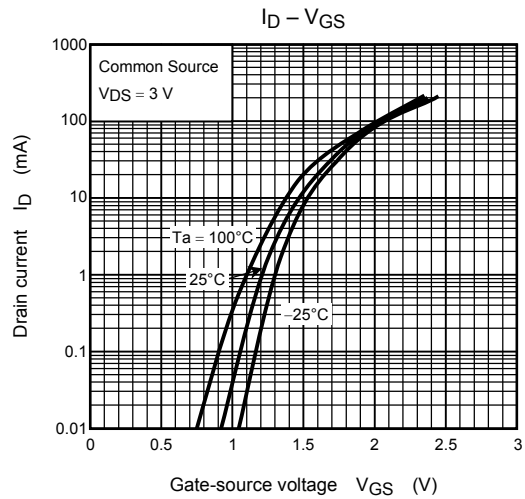
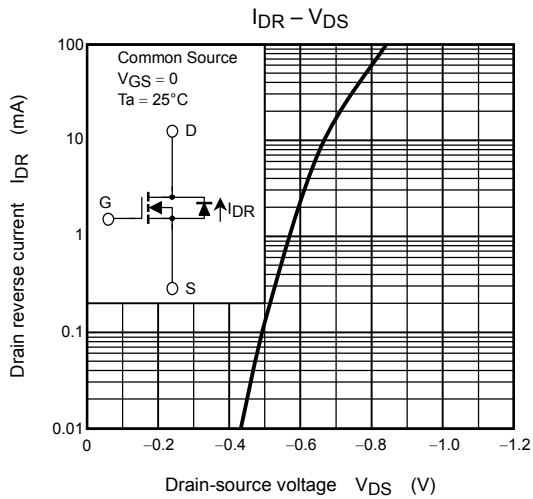
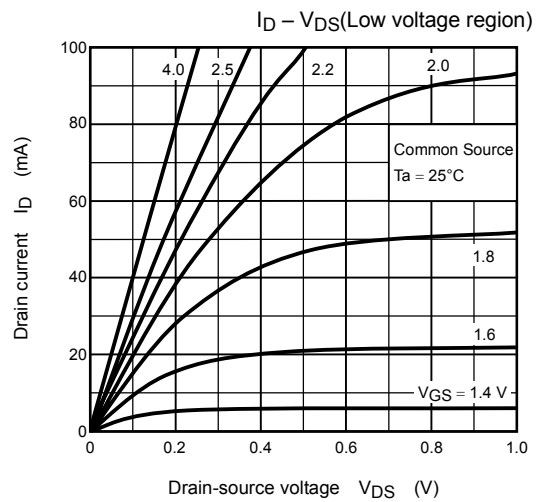
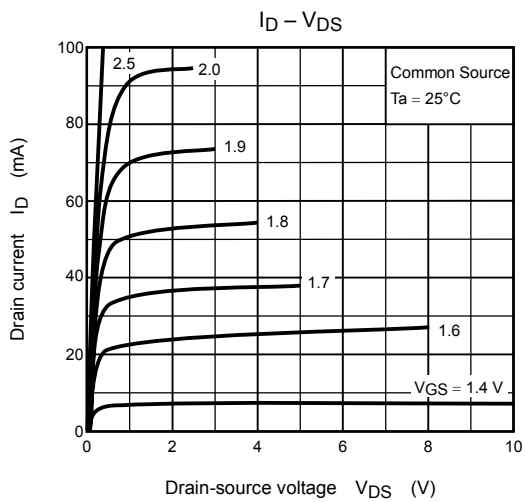


Precaution

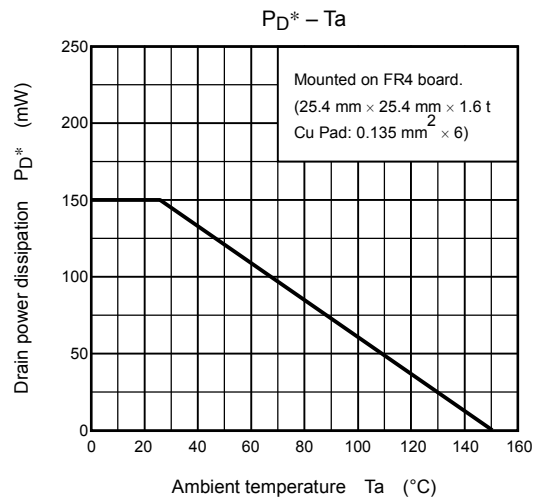
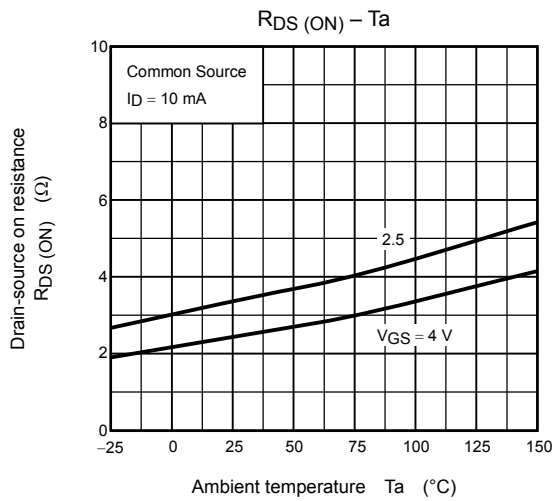
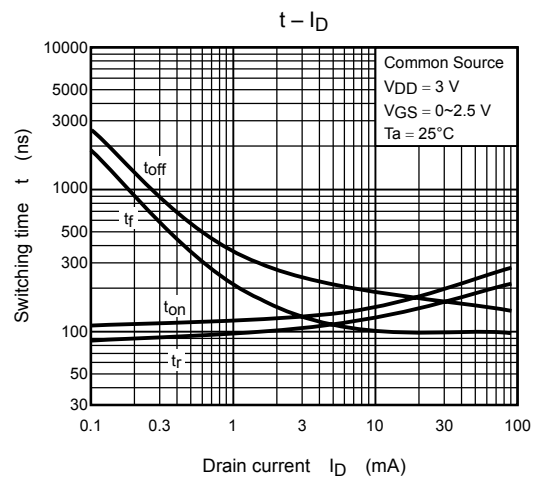
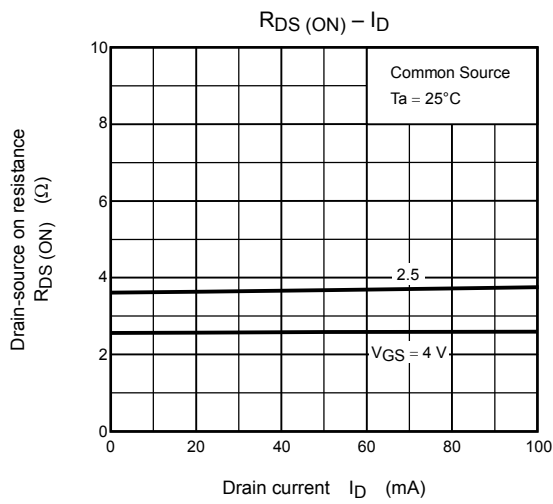
V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = 100\ \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(OFF)}$ requires lower voltage than V_{th} . (Relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device. V_{GS} recommended voltage of 2.5 V or higher to turn on this product.

(Q1, Q2 Common)



(Q1, Q2 Common)



*: Total rating

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.